Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-386-6173

| Inclosure Material: |
|--|
| Metal |
| Overall Length: |
| 0.150 inches |
| Semiconductor Material: |
| Gallium phosphide |
| Special Features: |
| Light output is 0.6 to 0.8 microlamberts at 520 nanometers |
| Nuclear Hardness Critical Feature: |
| Hardened |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |

Yes - demil/mli

Fiig:

A110a0